



TS482

100mW STEREO HEADPHONE AMPLIFIER

- Operating from $V_{CC}=2V$ to $5.5V$
- 100mW into 16Ω at $5V$
- 38mW into 16Ω at $3.3V$
- 11.5mW into 16Ω at $2V$
- Switch ON/OFF click reduction circuitry
- High Power Supply Rejection Ratio: 85dB at $5V$
- High Signal-to-Noise ratio: 110dB(A) at $5V$
- High Crosstalk immunity: 100dB ($F=1kHz$)
- Rail to Rail input and output
- Unity-Gain Stable
- Available in SO8, MiniSO8 & DFN8

DESCRIPTION

The TS482 is a dual audio power amplifier able to drive a 16 or 32Ω stereo headset down to low voltages.

It's delivering up to 100mW per channel (into 16Ω loads) of continuous average power with 0.1% THD+N from a $5V$ power supply.

The unity gain stable TS482 can be configured by external gain-setting resistors.

APPLICATIONS

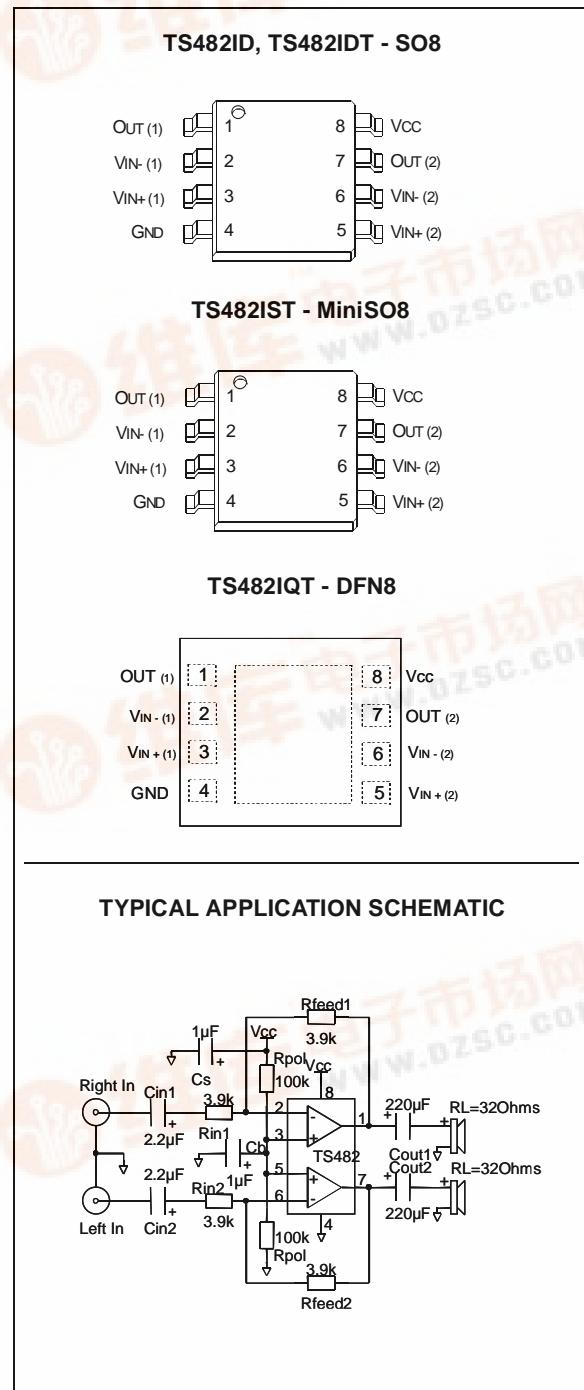
- Stereo Headphone Amplifier
- Optical Storage
- Computer Motherboard
- PDA, organizers & Notebook computers
- High end TV, Set Top Box, DVD Players
- Sound Cards

ORDER CODE

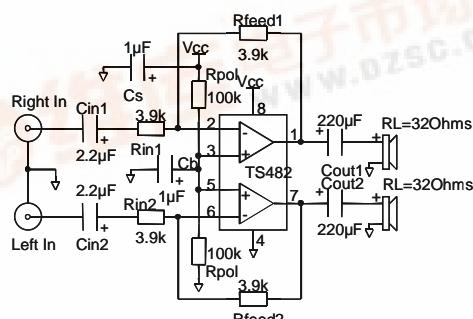
| Part Number | Temperature Range | Package | | | Marking |
|-------------|-------------------|---------|---|---|---------|
| | | D | S | Q | |
| TS482ID/DT | | • | | | |
| TS482IST | -40, +85°C | | • | | 482I |
| TS482IQT | | | | • | |

MiniSO & DFN only available in Tape & Reel with T suffix,
SO is available in Tube (D) and in Tape & Reel (DT))

PIN CONNECTIONS (top view)



TYPICAL APPLICATION SCHEMATIC



TS482

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|------------|--|------------------------|------|
| V_{CC} | Supply voltage ¹⁾ | 6 | V |
| V_i | Input Voltage | -0.3 to $V_{CC} + 0.3$ | V |
| T_{oper} | Operating Free Air Temperature Range | -40 to +85 | °C |
| T_{stg} | Storage Temperature | -65 to +150 | °C |
| T_j | Maximum Junction Temperature | 150 | °C |
| R_{thja} | Thermal Resistance Junction to Ambient SO8 MiniSO8 DFN8 | 175 215 70 | °C/W |
| Pd | Power Dissipation ²⁾ SO8 MiniSO8 DFN8 | 0.71 0.58 1.79 | W |
| ESD | Human Body Model (pin to pin) | 2 | kV |
| ESD | Machine Model - 220pF - 240pF (pin to pin) | 200 | V |
| Latch-up | Latch-up Immunity (All pins) | 200 | mA |
| | Lead Temperature (soldering, 10sec) | 250 | °C |
| | Output Short-Circuit Duration | see note ³⁾ | |

1. All voltages values are measured with respect to the ground pin.

2. Pd has been calculated with $T_{amb} = 25^\circ\text{C}$, $T_{junction} = 150^\circ\text{C}$.

3. Attention must be paid to continuous power dissipation. Exposure of the IC to a short circuit on one or two amplifiers simultaneously can cause excessive heating and the destruction of the device.

OPERATING CONDITIONS

| Symbol | Parameter | Value | Unit |
|------------|--|----------------------|------|
| V_{CC} | Supply Voltage | 2 to 5.5 | V |
| R_L | Load Resistor | ≥ 16 | Ω |
| C_L | Load Capacitor $R_L = 16 \text{ to } 100\Omega$ $R_L > 100\Omega$ | 400 100 | pF |
| V_{ICM} | Common Mode Input Voltage Range | G_{ND} to V_{CC} | V |
| R_{THJA} | Thermal Resistance Junction to Ambient SO8 MiniSO8 DFN8 ¹⁾ | 150 190 41 | °C/W |

1. When mounted on a 4-layer PCB.

| Components | Functional Description |
|------------|--|
| R_{in} | Inverting input resistor which sets the closed loop gain in conjunction with R_{feed} . This resistor also forms a high pass filter with C_{in} ($f_c = 1 / (2 \times \pi \times R_{in} \times C_{in})$) |
| C_{in} | Input coupling capacitor which blocks the DC voltage at the amplifier input terminal |
| R_{feed} | Feed back resistor which sets the closed loop gain in conjunction with R_{in} |
| C_s | Supply Bypass capacitor which provides power supply filtering |
| C_b | Bypass capacitor which provides half supply filtering |
| C_{out} | Output coupling capacitor which blocks the DC voltage at the load input terminal This capacitor also forms a high pass filter with R_L ($f_c = 1 / (2 \times \pi \times R_L \times C_{out})$) |
| R_{pol} | These 2 resistors form a voltage divider which provide a DC biasing voltage ($V_{cc}/2$) for the 2 amplifiers. |
| A_v | Closed loop gain = $-R_{feed} / R_{in}$ |

ELECTRICAL CHARACTERISTICS $V_{CC} = +5V$, GND = 0V, $T_{amb} = 25^\circ C$ (unless otherwise specified)

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
|-----------|--|----------|--------------------------|---------------------------|--------------|
| I_{CC} | Supply Current No input signal, no load | | 5.5 | 7.2 | mA |
| V_{IO} | Input Offset Voltage ($V_{ICM} = V_{CC}/2$) | | 1 | 5 | mV |
| I_{IB} | Input Bias Current ($V_{ICM} = V_{CC}/2$) | | 200 | 500 | nA |
| P_O | Output Power $THD+N = 0.1\% \text{ Max}, F = 1\text{kHz}, R_L = 32\Omega$ $THD+N = 1\% \text{ Max}, F = 1\text{kHz}, R_L = 32\Omega$ $THD+N = 0.1\% \text{ Max}, F = 1\text{kHz}, R_L = 16\Omega$ $THD+N = 1\% \text{ Max}, F = 1\text{kHz}, R_L = 16\Omega$ | 60 95 | 65 67.5 100 107 | | mW |
| THD + N | Total Harmonic Distortion + Noise ($A_v=-1$) $R_L = 32\Omega, P_{out} = 60\text{mW}, 20\text{Hz} \leq F \leq 20\text{kHz}$ $R_L = 16\Omega, P_{out} = 90\text{mW}, 20\text{Hz} \leq F \leq 20\text{kHz}$ | | 0.03 0.03 | | % |
| PSRR | Power Supply Rejection Ratio ($A_v=1$), inputs floating $F = 100\text{Hz}, \text{Vripple} = 100\text{mVpp}$ | | 85 | | dB |
| I_O | Max Output Current $THD + N < 1\%, R_L = 16\Omega$ connected between out and $V_{CC}/2$ | 106 | 120 | | mA |
| V_O | Output Swing $V_{OL} : R_L = 32\Omega$ $V_{OH} : R_L = 32\Omega$ $V_{OL} : R_L = 16\Omega$ $V_{OH} : R_L = 16\Omega$ | | 4.45 4.2 | 0.4 4.6 0.55 4.4 | 0.48 0.65 |
| SNR | Signal-to-Noise Ratio (Filter Type A, $A_v=-1$) ($R_L = 32\Omega$, THD + N < 0.2%, 20Hz $\leq F \leq 20\text{kHz}$) | 95 | 110 | | dB |
| Crosstalk | Channel Separation, $R_L = 32\Omega$ $F = 1\text{kHz}$ $F = 20\text{Hz} \text{ to } 20\text{kHz}$ Channel Separation, $R_L = 16\Omega$ $F = 1\text{kHz}$ $F = 20\text{Hz} \text{ to } 20\text{kHz}$ | | | 100 80 100 80 | |
| C_I | Input Capacitance | | 1 | | pF |
| GBP | Gain Bandwidth Product ($R_L = 32\Omega$) | 1.35 | 2.2 | | MHz |
| SR | Slew Rate, Unity Gain Inverting ($R_L = 16\Omega$) | 0.45 | 0.7 | | V/ μ s |

1. Fig. 68 to 79 show dispersion of these parameters.

ELECTRICAL CHARACTERISTICS $V_{CC} = +3.3V$, GND = 0V, $T_{amb} = 25^\circ C$ (unless otherwise specified)²⁾

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
|-----------|--|--------------|--------------------------|--------------|------|
| I_{CC} | Supply Current No input signal, no load | | 5.3 | 7.2 | mA |
| V_{IO} | Input Offset Voltage ($V_{ICM} = V_{CC}/2$) | | 1 | 5 | mV |
| I_{IB} | Input Bias Current ($V_{ICM} = V_{CC}/2$) | | 200 | 500 | nA |
| P_O | Output Power $THD+N = 0.1\% \text{ Max}, F = 1\text{kHz}, R_L = 32\Omega$ $THD+N = 1\% \text{ Max}, F = 1\text{kHz}, R_L = 32\Omega$ $THD+N = 0.1\% \text{ Max}, F = 1\text{kHz}, R_L = 16\Omega$ $THD+N = 1\% \text{ Max}, F = 1\text{kHz}, R_L = 16\Omega$ | 23 36 | 27 28 38 42 | | mW |
| THD + N | Total Harmonic Distortion + Noise ($A_v=-1$) $R_L = 32\Omega, P_{out} = 16\text{mW}, 20\text{Hz} \leq F \leq 20\text{kHz}$ $R_L = 16\Omega, P_{out} = 35\text{mW}, 20\text{Hz} \leq F \leq 20\text{kHz}$ | | 0.03 0.03 | | % |
| PSRR | Power Supply Rejection Ratio ($A_v=1$), inputs floating $F = 100\text{Hz}, \text{Vripple} = 100\text{mVpp}$ | | 80 | | dB |
| I_O | Max Output Current $THD + N < 1\%, R_L = 16\Omega$ connected between out and $V_{CC}/2$ | 64 | 75 | | mA |
| V_O | Output Swing $V_{OL} : R_L = 32\Omega$ $V_{OH} : R_L = 32\Omega$ $V_{OL} : R_L = 16\Omega$ $V_{OH} : R_L = 16\Omega$ | 2.85 2.68 | 0.3 3 0.45 0.52 | 0.38 0.52 | V |
| SNR | Signal-to-Noise Ratio (Filter Type A, $A_v=-1$) ($R_L = 32\Omega$, THD + N < 0.2%, 20Hz ≤ F ≤ 20kHz) | 92 | 107 | | dB |
| Crosstalk | Channel Separation, $R_L = 32\Omega$ $F = 1\text{kHz}$ $F = 20\text{Hz} \text{ to } 20\text{kHz}$ Channel Separation, $R_L = 16\Omega$ $F = 1\text{kHz}$ $F = 20\text{Hz} \text{ to } 20\text{kHz}$ | | 100 80 100 80 | | dB |
| C_I | Input Capacitance | | 1 | | pF |
| GBP | Gain Bandwidth Product ($R_L = 32\Omega$) | 1.2 | 2 | | MHz |
| SR | Slew Rate, Unity Gain Inverting ($R_L = 16\Omega$) | 0.45 | 0.7 | | V/μs |

1. Fig. 68 to 79 show dispersion of these parameters.

2. All electrical values are guaranteed with correlation measurements at 2V and 5V

ELECTRICAL CHARACTERISTICS $V_{CC} = +2.5V$, GND = 0V, $T_{amb} = 25^\circ C$ (unless otherwise specified)²⁾

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
|-----------|--|--------------|------------------------------|---------------|------|
| I_{CC} | Supply Current No input signal, no load | | 5.1 | 7.2 | mA |
| V_{IO} | Input Offset Voltage ($V_{ICM} = V_{CC}/2$) | | 1 | 5 | mV |
| I_{IB} | Input Bias Current ($V_{ICM} = V_{CC}/2$) | | 200 | 500 | nA |
| P_O | Output Power $THD+N = 0.1\% \text{ Max}, F = 1\text{kHz}, R_L = 32\Omega$ $THD+N = 1\% \text{ Max}, F = 1\text{kHz}, R_L = 32\Omega$ $THD+N = 0.1\% \text{ Max}, F = 1\text{kHz}, R_L = 16\Omega$ $THD+N = 1\% \text{ Max}, F = 1\text{kHz}, R_L = 16\Omega$ | 12.5 17.5 | 13.5 14.5 20.5 22 | | mW |
| THD + N | Total Harmonic Distortion + Noise ($A_v=-1$) $R_L = 32\Omega, P_{out} = 10\text{mW}, 20\text{Hz} \leq F \leq 20\text{kHz}$ $R_L = 16\Omega, P_{out} = 16\text{mW}, 20\text{Hz} \leq F \leq 20\text{kHz}$ | | 0.03 0.03 | | % |
| PSRR | Power Supply Rejection Ratio ($A_v=1$), inputs floating $F = 100\text{Hz}, \text{Vripple} = 100\text{mVpp}$ | | 75 | | dB |
| I_O | Max Output Current $THD + N < 1\%, R_L = 16\Omega$ connected between out and $V_{CC}/2$ | 45 | 56 | | mA |
| V_O | Output Swing $V_{OL} : R_L = 32\Omega$ $V_{OH} : R_L = 32\Omega$ $V_{OL} : R_L = 16\Omega$ $V_{OH} : R_L = 16\Omega$ | 2.14 1.97 | 0.25 2.25 0.35 2.15 | 0.325 0.45 | V |
| SNR | Signal-to-Noise Ratio (Filter Type A, $A_v=-1$) ($R_L = 32\Omega$, THD + N < 0.2%, 20Hz ≤ F ≤ 20kHz) | 89 | 102 | | dB |
| Crosstalk | Channel Separation, $R_L = 32\Omega$ $F = 1\text{kHz}$ $F = 20\text{Hz} \text{ to } 20\text{kHz}$ Channel Separation, $R_L = 16\Omega$ $F = 1\text{kHz}$ $F = 20\text{Hz} \text{ to } 20\text{kHz}$ | | 100 80 100 80 | | dB |
| C_I | Input Capacitance | | 1 | | pF |
| GBP | Gain Bandwidth Product ($R_L = 32\Omega$) | 1.2 | 2 | | MHz |
| SR | Slew Rate, Unity Gain Inverting ($R_L = 16\Omega$) | 0.45 | 0.7 | | V/μs |

1. Fig. 68 to 79 show dispersion of these parameters.

2. All electrical values are guaranteed with correlation measurements at 2V and 5V

ELECTRICAL CHARACTERISTICS $V_{CC} = +2V$, GND = 0V, $T_{amb} = 25^\circ C$ (unless otherwise specified)

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
|-----------|--|----------|----------------------|------------------------------|---------------|
| I_{CC} | Supply Current No input signal, no load | | 5 | 7.2 | mA |
| V_{IO} | Input Offset Voltage ($V_{ICM} = V_{CC}/2$) | | 1 | 5 | mV |
| I_{IB} | Input Bias Current ($V_{ICM} = V_{CC}/2$) | | 200 | 500 | nA |
| P_O | Output Power $THD+N = 0.1\% \text{ Max}, F = 1\text{kHz}, R_L = 32\Omega$ $THD+N = 1\% \text{ Max}, F = 1\text{kHz}, R_L = 32\Omega$ $THD+N = 0.1\% \text{ Max}, F = 1\text{kHz}, R_L = 16\Omega$ $THD+N = 1\% \text{ Max}, F = 1\text{kHz}, R_L = 16\Omega$ | 7 9.5 | 8 9 11.5 13 | | mW |
| THD + N | Total Harmonic Distortion + Noise ($A_v=-1$) $R_L = 32\Omega, P_{out} = 6.5\text{mW}, 20\text{Hz} \leq F \leq 20\text{kHz}$ $R_L = 16\Omega, P_{out} = 8\text{mW}, 20\text{Hz} \leq F \leq 20\text{kHz}$ | | 0.02 0.025 | | % |
| PSRR | Power Supply Rejection Ratio ($A_v=1$), inputs floating $F = 100\text{Hz}, \text{Vripple} = 100\text{mVpp}$ | | 75 | | dB |
| I_O | Max Output Current $THD +N < 1\%, R_L = 16\Omega$ connected between out and $V_{CC}/2$ | 33 | 41.5 | | mA |
| V_O | Output Swing $V_{OL} : R_L = 32\Omega$ $V_{OH} : R_L = 32\Omega$ $V_{OL} : R_L = 16\Omega$ $V_{OH} : R_L = 16\Omega$ | | 1.67 1.53 | 0.24 1.73 0.33 1.63 | 0.295 0.41 |
| SNR | Signal-to-Noise Ratio (Filter Type A, $A_v=-1$) ($R_L = 32\Omega, THD +N < 0.2\%, 20\text{Hz} \leq F \leq 20\text{kHz}$) | 88 | 101 | | dB |
| Crosstalk | Channel Separation, $R_L = 32\Omega$ $F = 1\text{kHz}$ $F = 20\text{Hz} \text{ to } 20\text{kHz}$ Channel Separation, $R_L = 16\Omega$ $F = 1\text{kHz}$ $F = 20\text{Hz} \text{ to } 20\text{kHz}$ | | | 100 80 100 80 | dB |
| C_I | Input Capacitance | | 1 | | pF |
| GBP | Gain Bandwidth Product ($R_L = 32\Omega$) | 1.2 | 2 | | MHz |
| SR | Slew Rate, Unity Gain Inverting ($R_L = 16\Omega$) | 0.42 | 0.65 | | V/ μ s |

1. Fig. 68 to 79 show dispersion of these parameters.

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TS482

Fig. 1 : Open Loop Gain and Phase vs Frequency

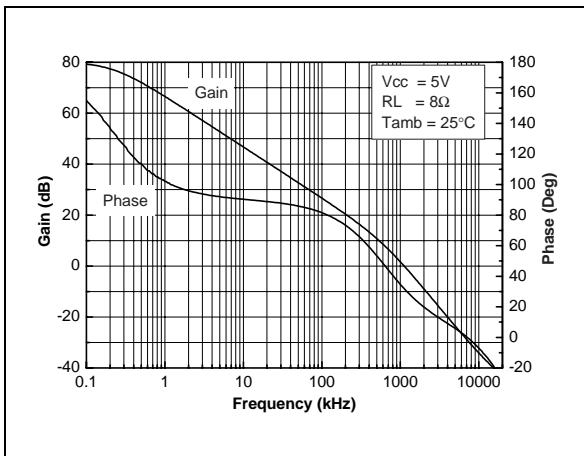


Fig. 2 : Open Loop Gain and Phase vs Frequency

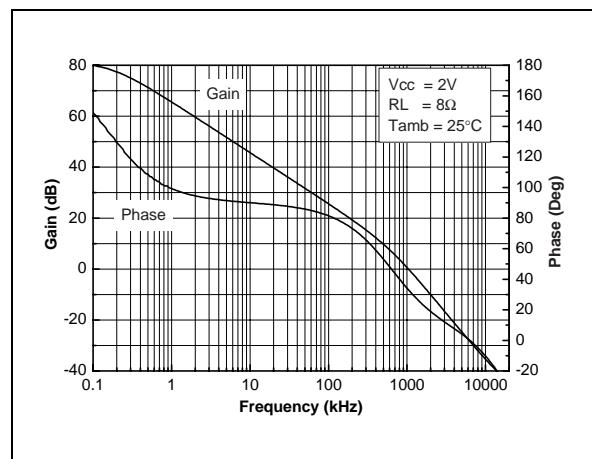


Fig. 3 : Open Loop Gain and Phase vs Frequency

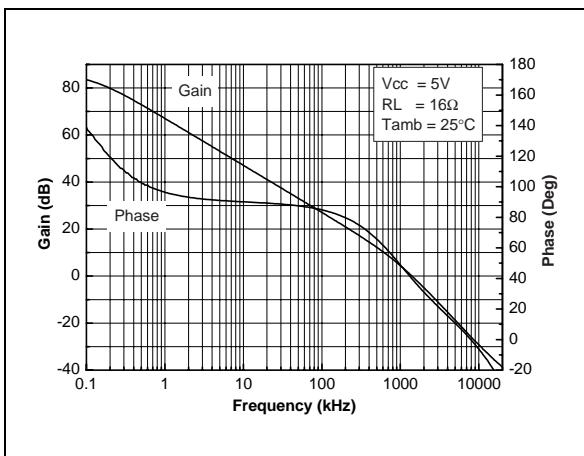


Fig. 4 : Open Loop Gain and Phase vs Frequency

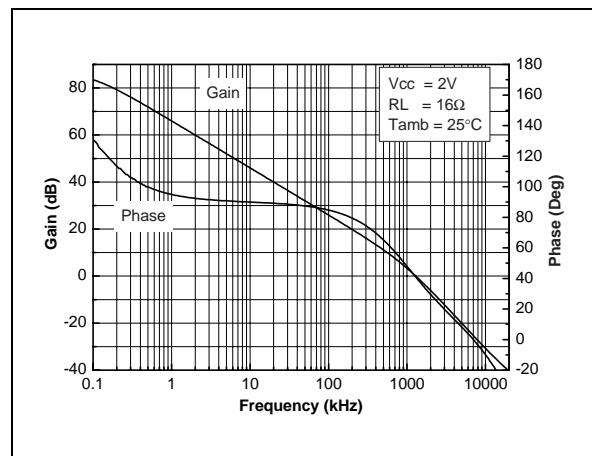


Fig. 5 : Open Loop Gain and Phase vs Frequency

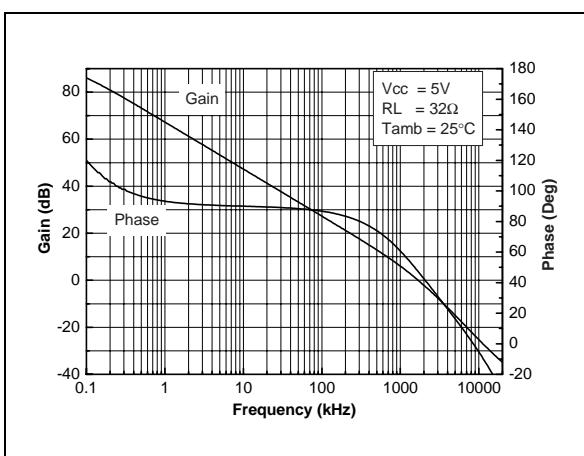


Fig. 6 : Open Loop Gain and Phase vs Frequency

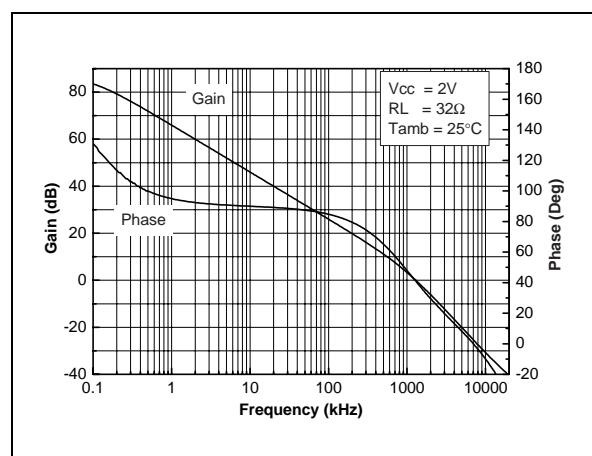


Fig. 7 : Open Loop Gain and Phase vs Frequency

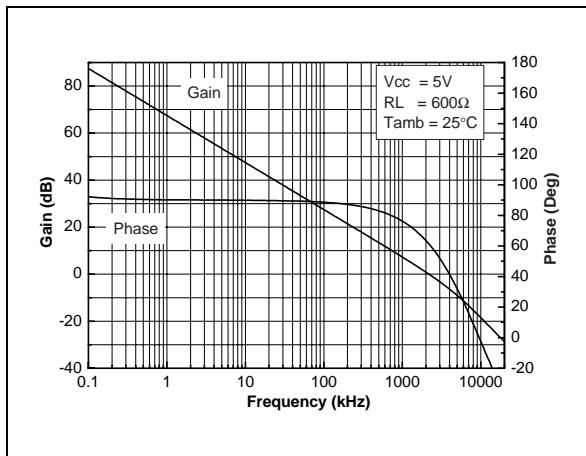


Fig. 8 : Open Loop Gain and Phase vs Frequency

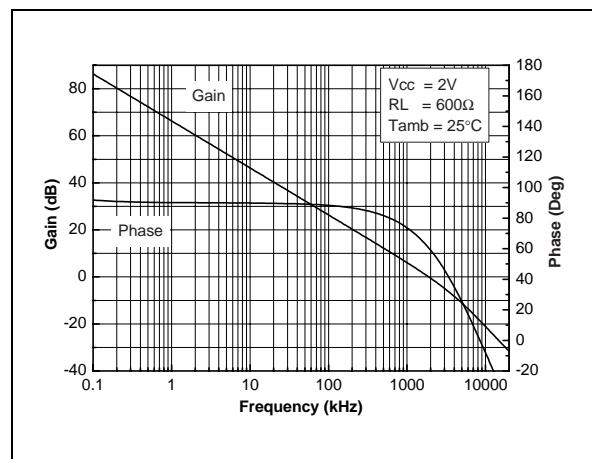


Fig. 9 : Open Loop Gain and Phase vs Frequency

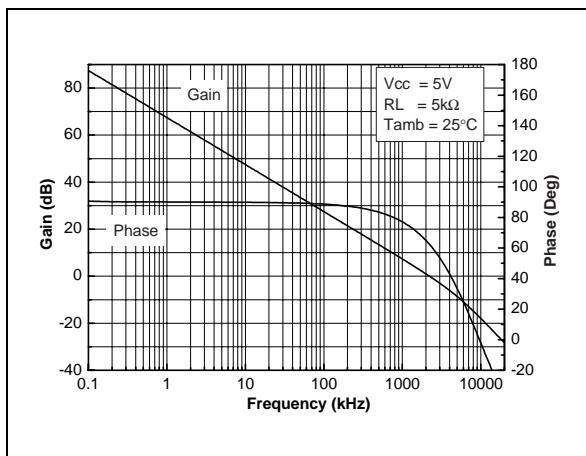


Fig. 10 : Open Loop Gain and Phase vs Frequency

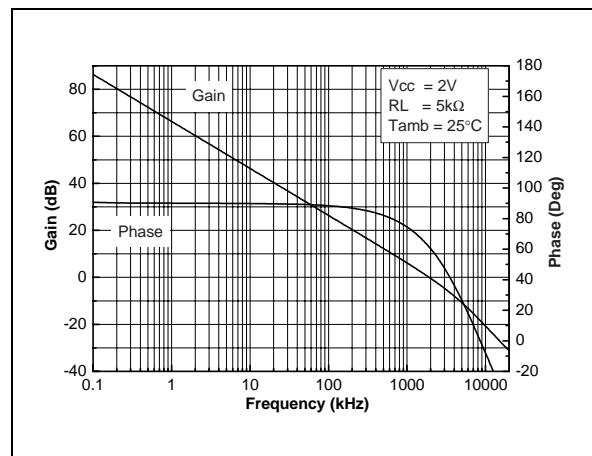


Fig. 11 : Phase Margin vs Power Supply Voltage

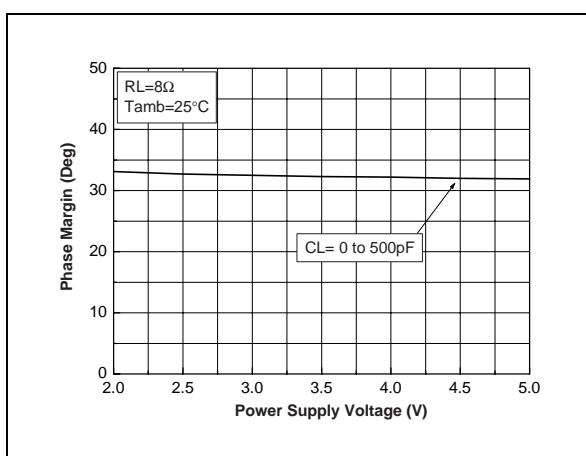
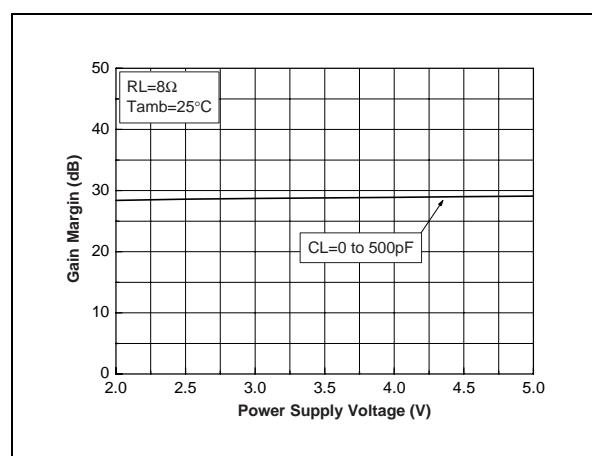


Fig. 12 : Gain Margin vs Power Supply Voltage



TS482

Fig. 13 : Phase Margin vs Power Supply Voltage

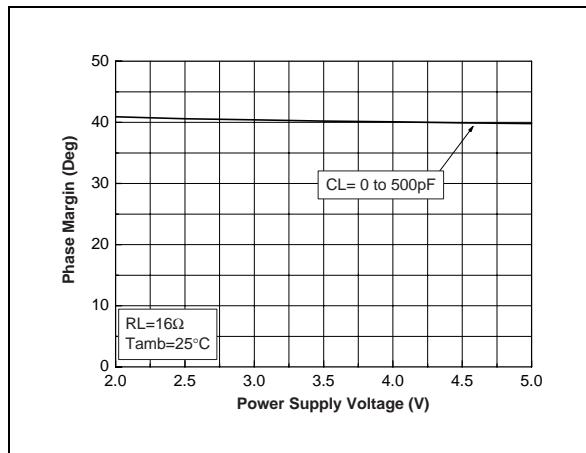


Fig. 14 : Gain Margin vs Power Supply Voltage

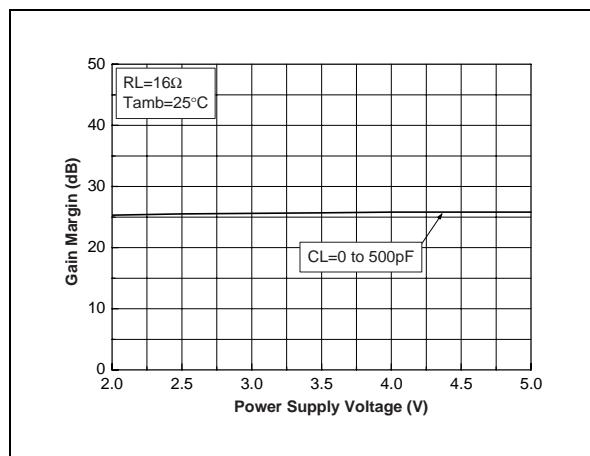


Fig. 15 : Phase Margin vs Power Supply Voltage

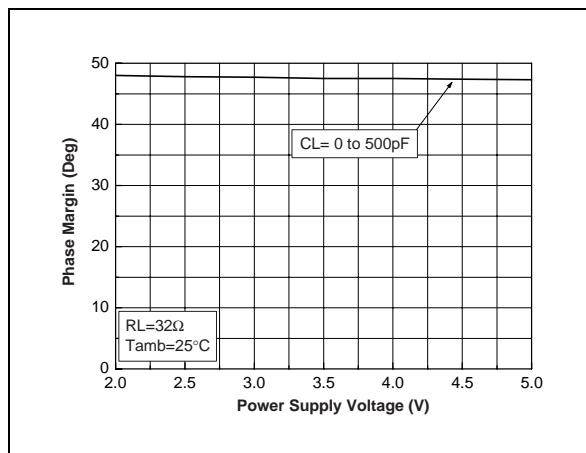


Fig. 16 : Gain Margin vs Power Supply Voltage

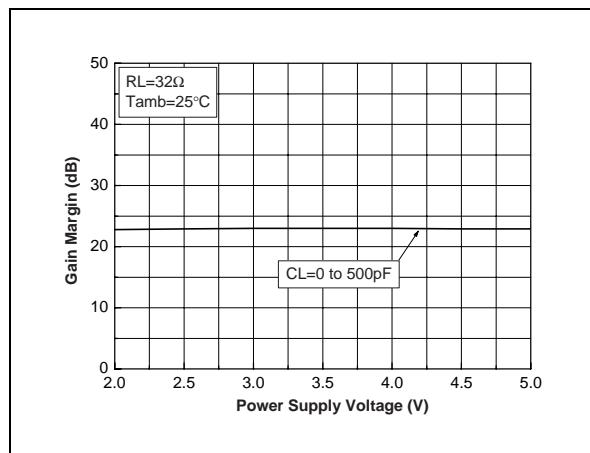


Fig. 17 : Phase Margin vs Power Supply Voltage

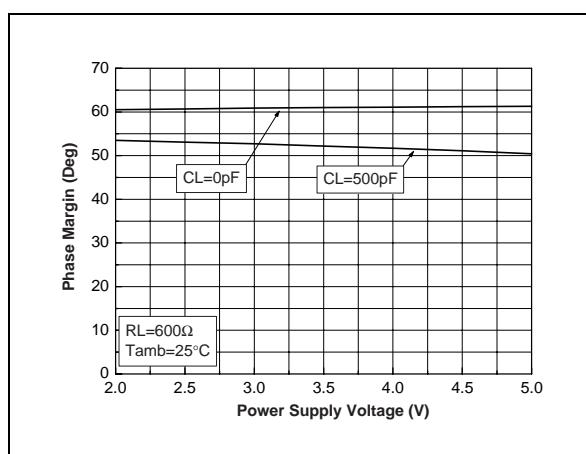


Fig. 18 : Gain Margin vs Power Supply Voltage

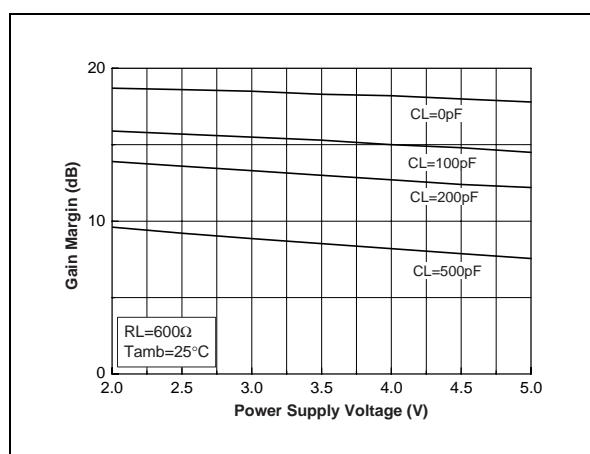


Fig. 19 : Phase Margin vs Power Supply Voltage

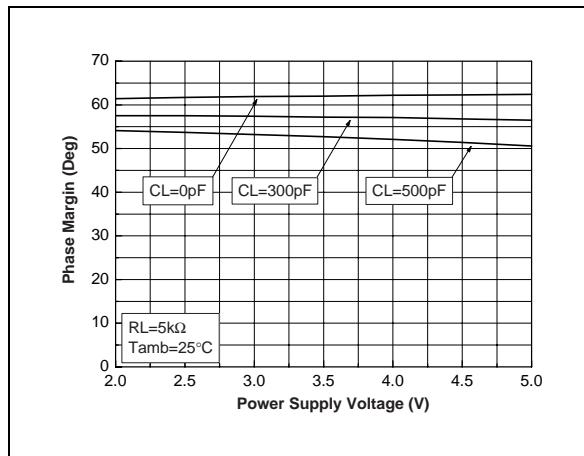


Fig. 20 : Gain Margin vs Power Supply Voltage

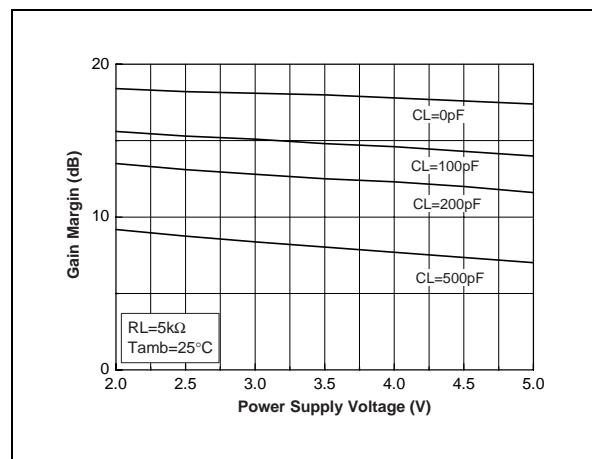


Fig. 21 : Output Power vs Power Supply Voltage

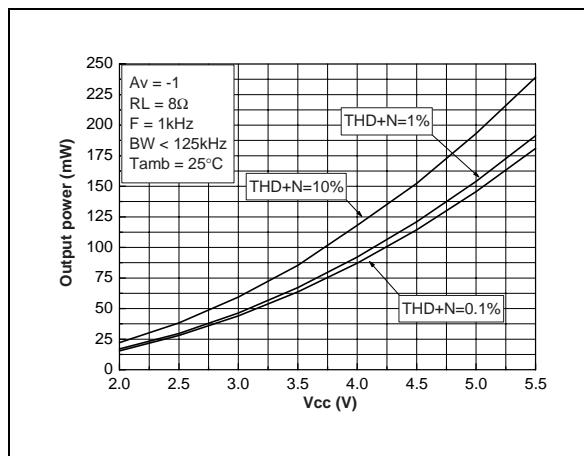


Fig. 22 : Output Power vs Power Supply Voltage

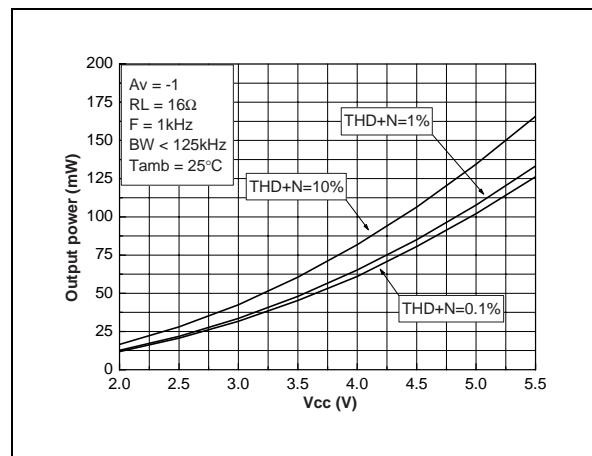


Fig. 23 :Output Power vs Power Supply Voltage

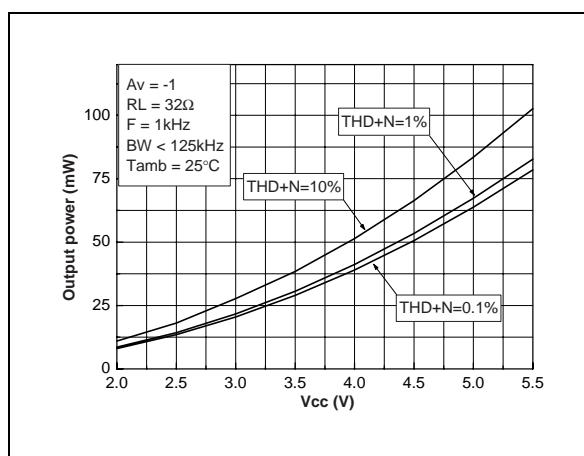
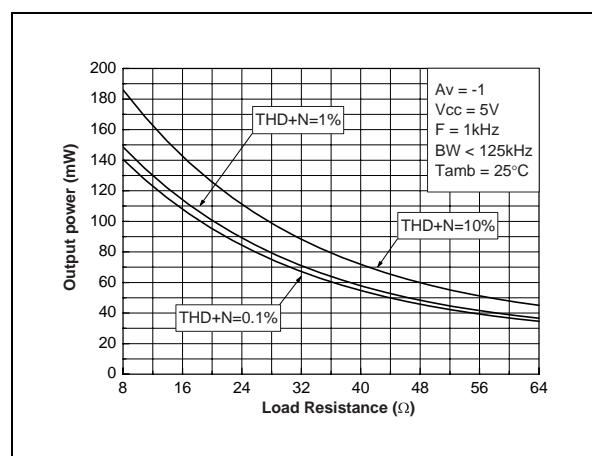


Fig. 24 : Output Power vs Load Resistance



TS482

Fig. 25 : Output Power vs Load Resistance

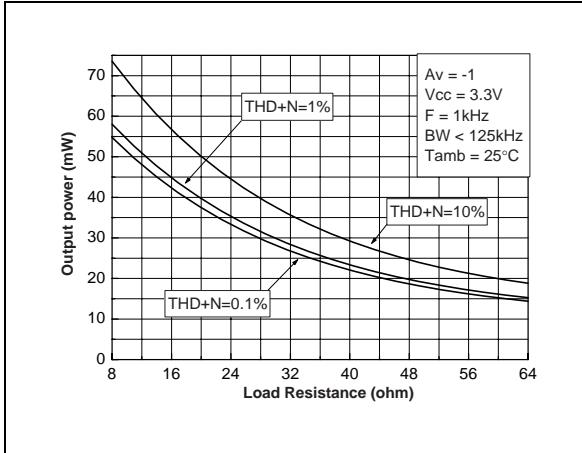


Fig. 27 : Output Power vs Load Resistance

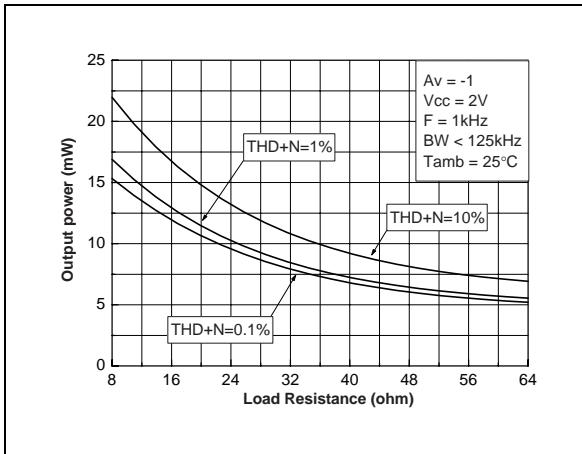


Fig. 29 : Power Dissipation vs Output Power

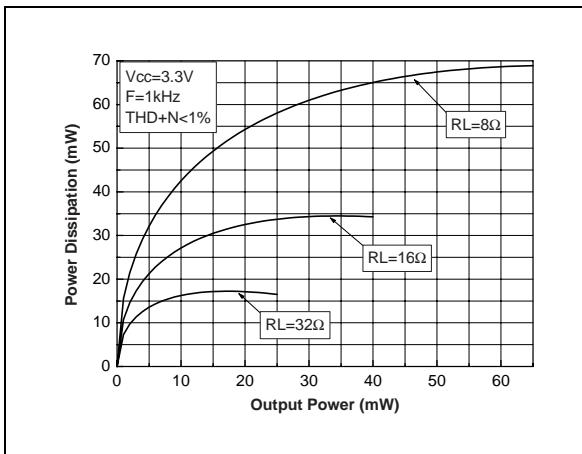


Fig. 26 : Output Power vs Load Resistance

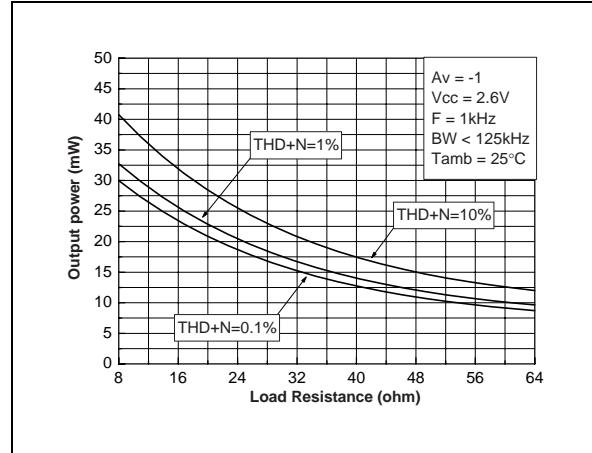


Fig. 28 : Power Dissipation vs Output Power

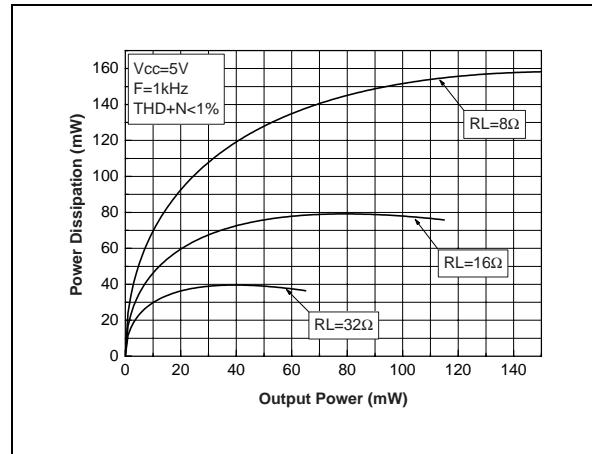


Fig. 30 : Power Dissipation vs Output Power

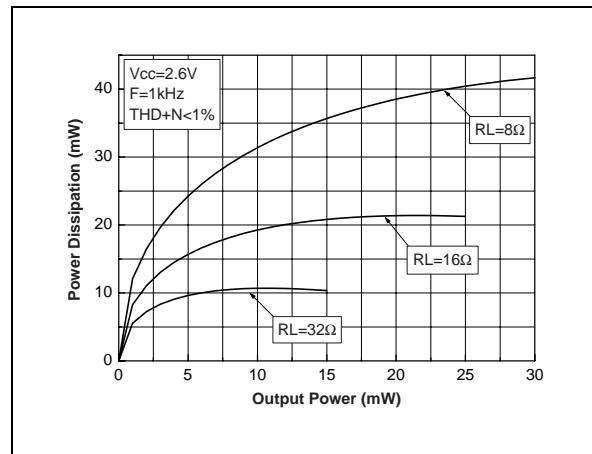
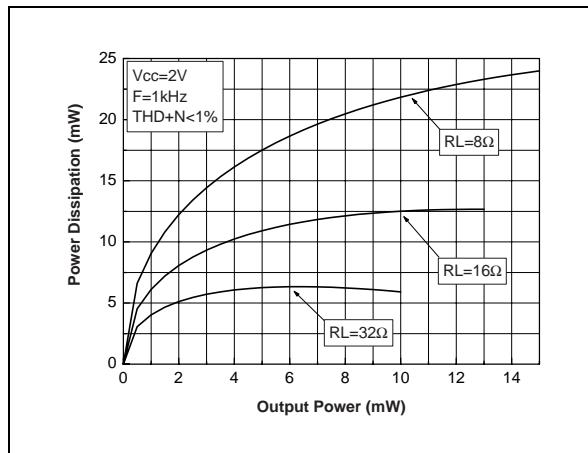
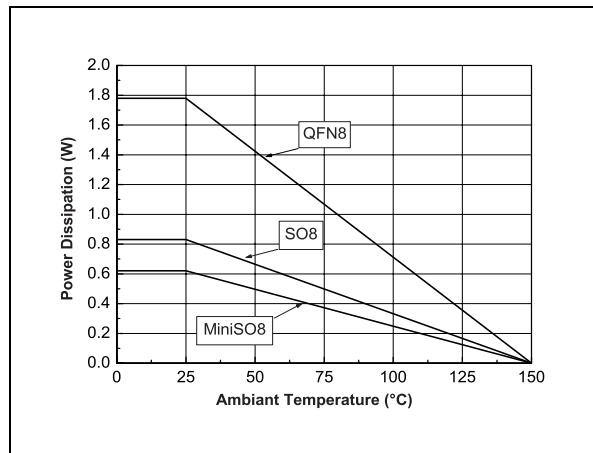
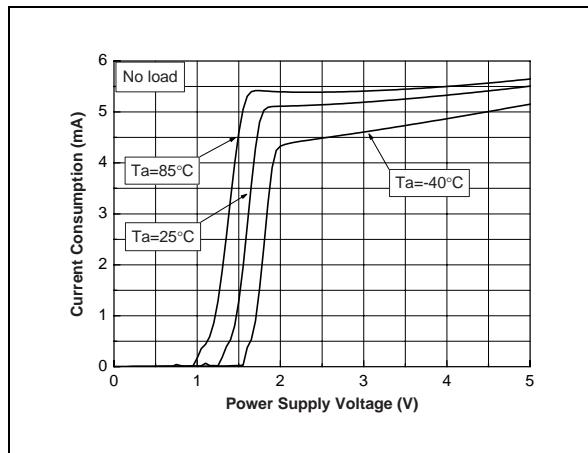
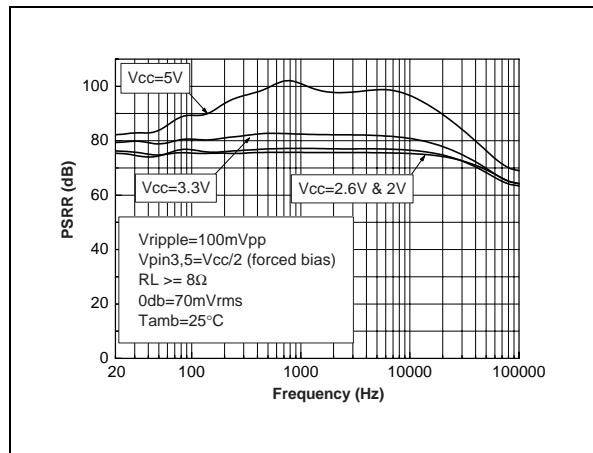
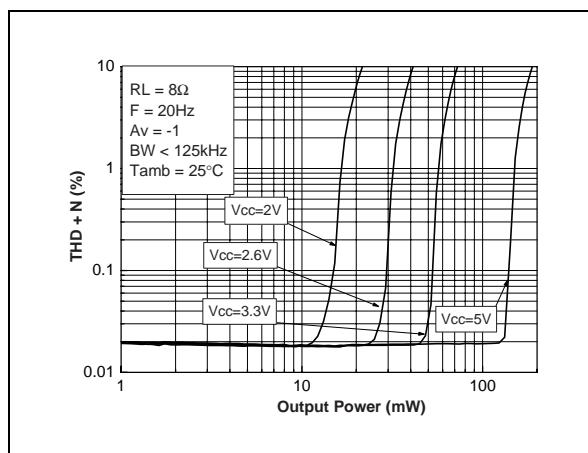
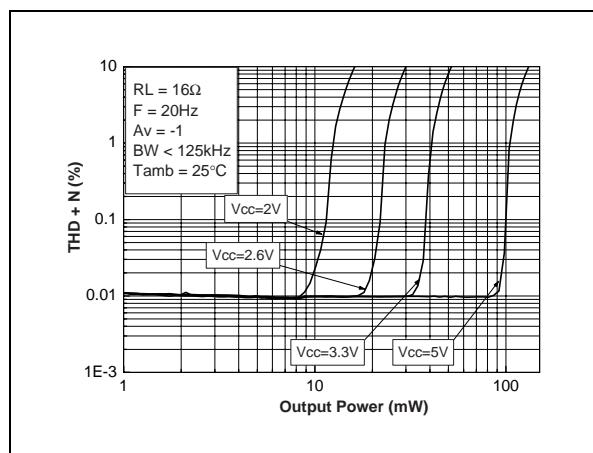


Fig. 31 : Power Dissipation vs Output Power**Fig. 32 : Power Derating vs Ambient Temperature****Fig. 33 : Current Consumption vs Power Supply Voltage****Fig. 34 : Power Supply Rejection Ration vs Frequency****Fig. 35 : THD + N vs Output Power****Fig. 36 : THD + N vs Output Power**

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Fig. 37 : THD + N vs Output Power

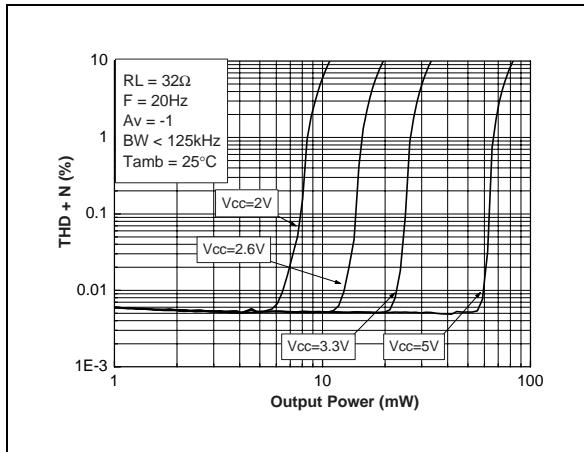


Fig. 38 : THD + N vs Output Power

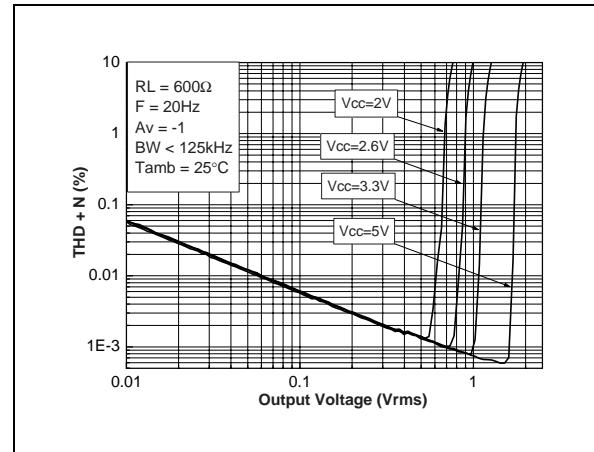


Fig. 39 : THD + N vs Output Power

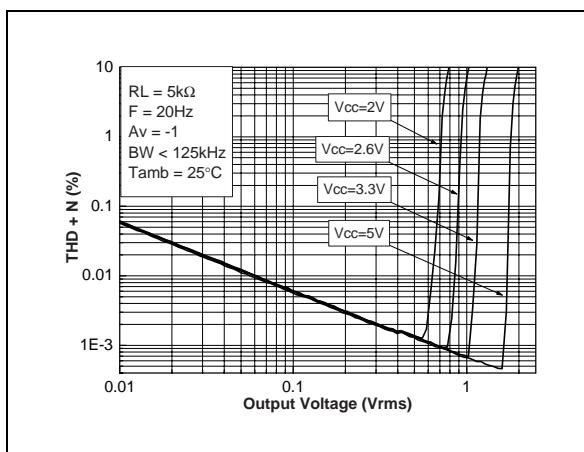


Fig. 40 : THD + N vs Output Power

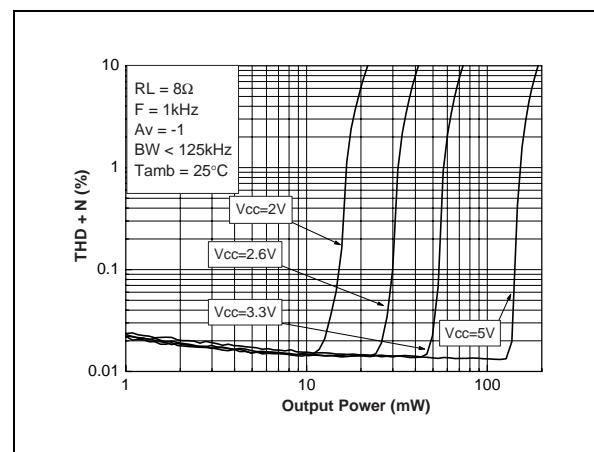


Fig. 41 : THD + N vs Output Power

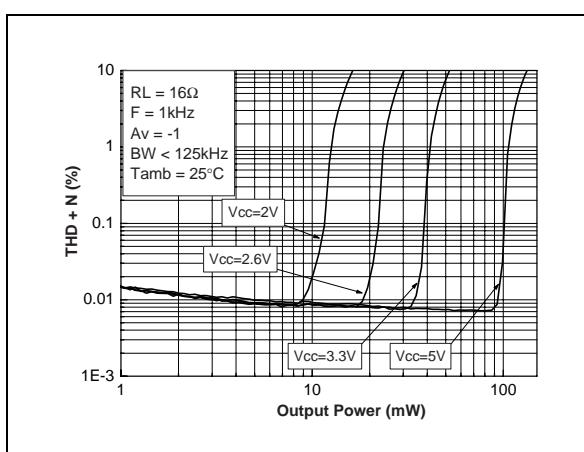


Fig. 42 : THD + N vs Output Power

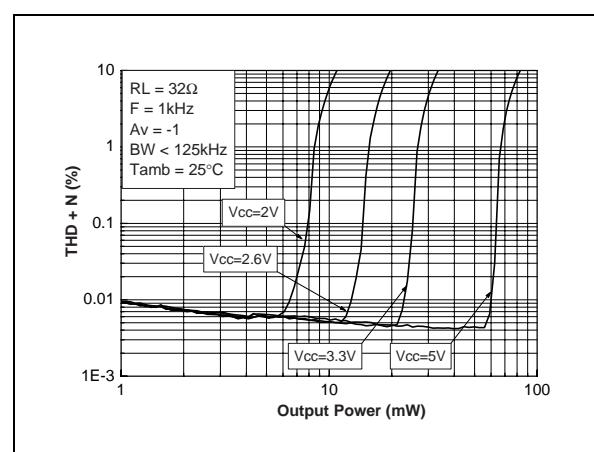


Fig. 43 : THD + N vs Output Power

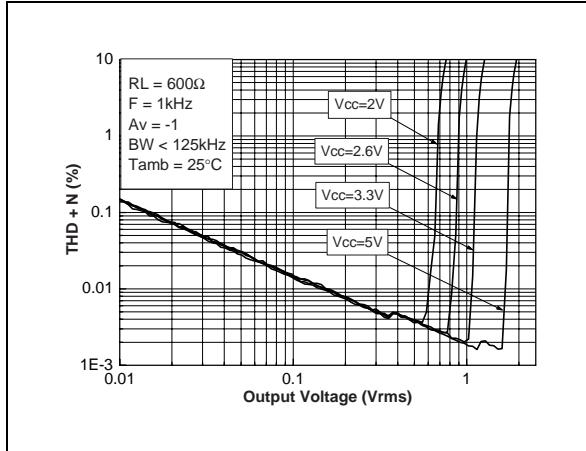


Fig. 44 : THD + N vs Output Power

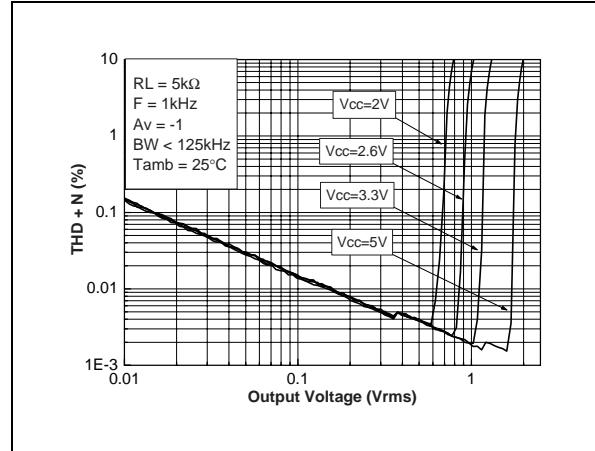


Fig. 45 : THD + N vs Output Power

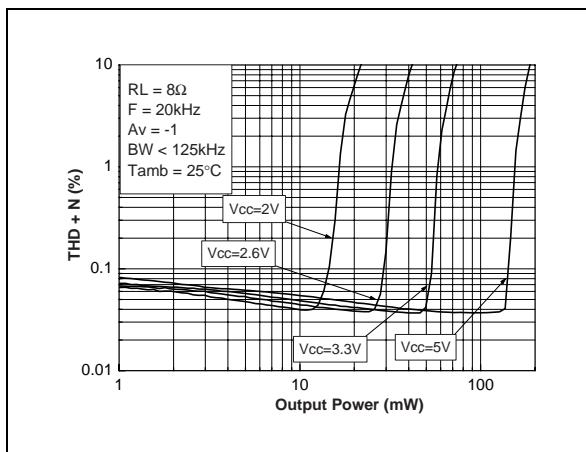


Fig. 46 : THD + N vs Output Power

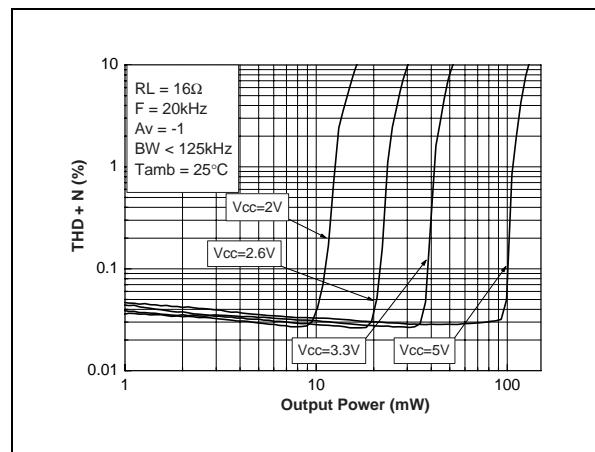


Fig. 47 : THD + N vs Output Power

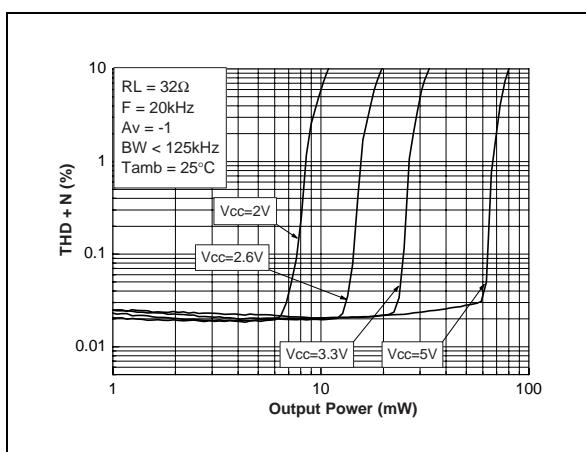
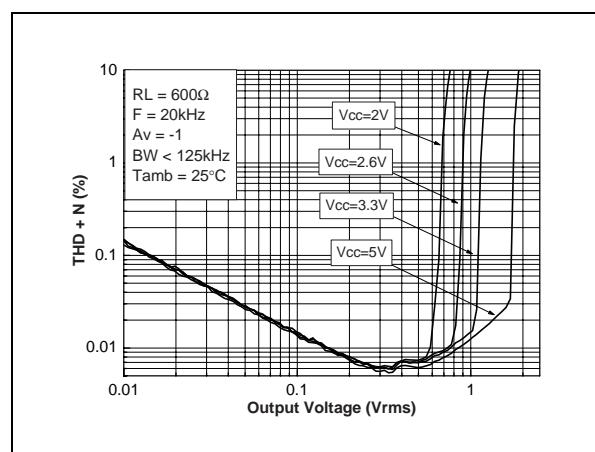


Fig. 48 : THD + N vs Output Power



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Fig. 49 : THD + N vs Output Power

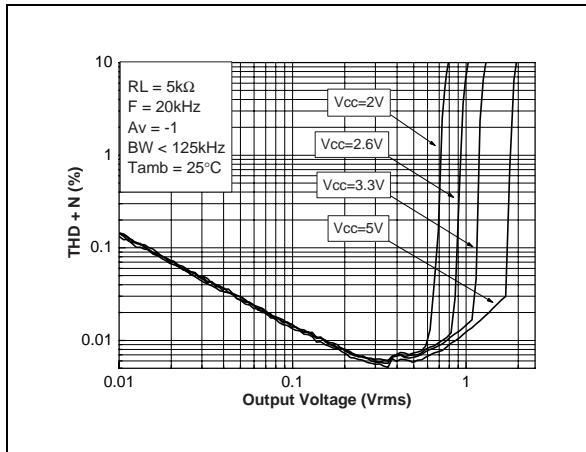


Fig. 50 : THD + N vs Frequency

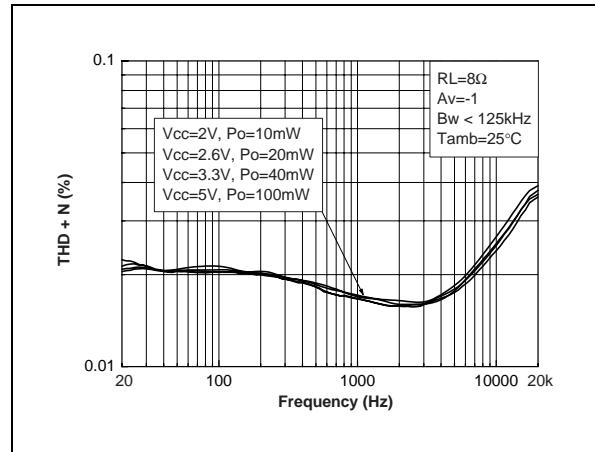


Fig. 51 : THD + N vs Frequency

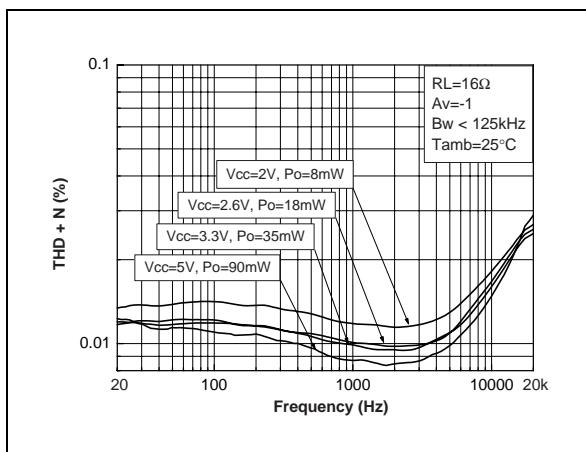


Fig. 52 : THD + N vs Frequency

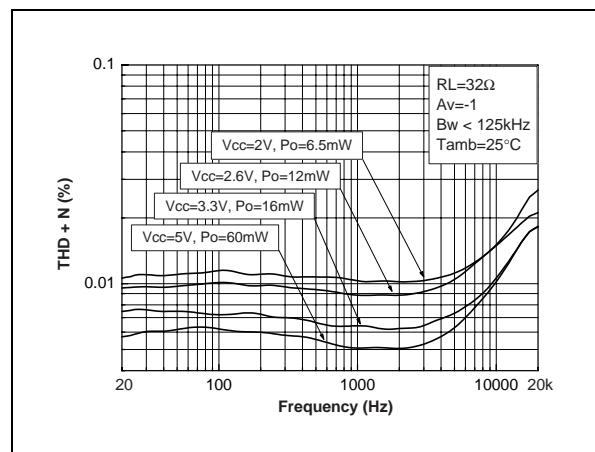


Fig. 53 : THD + N vs Frequency

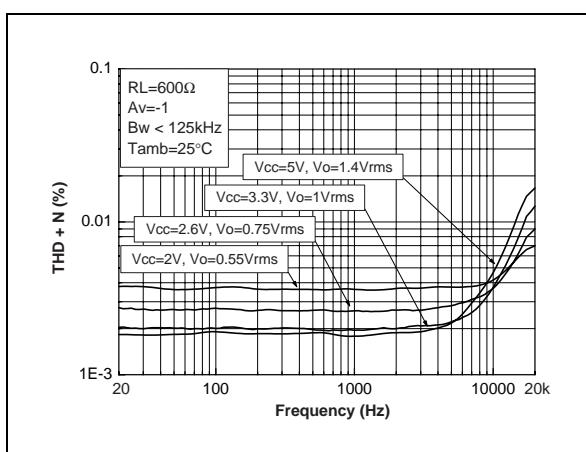


Fig. 54 : THD + N vs Frequency

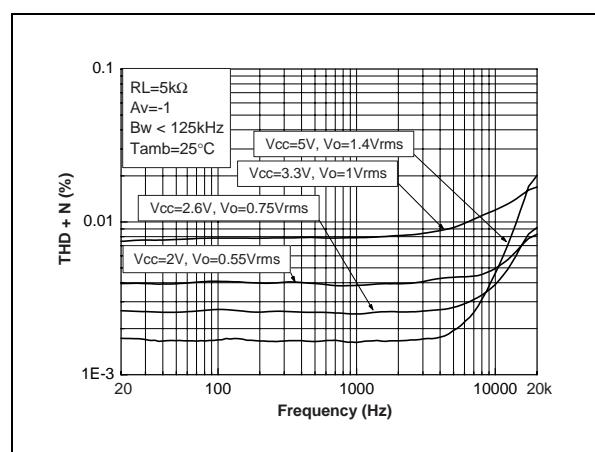


Fig. 55 : Signal to Noise Ratio vs Power Supply Voltage with Unweighted Filter (20Hz to 20kHz)

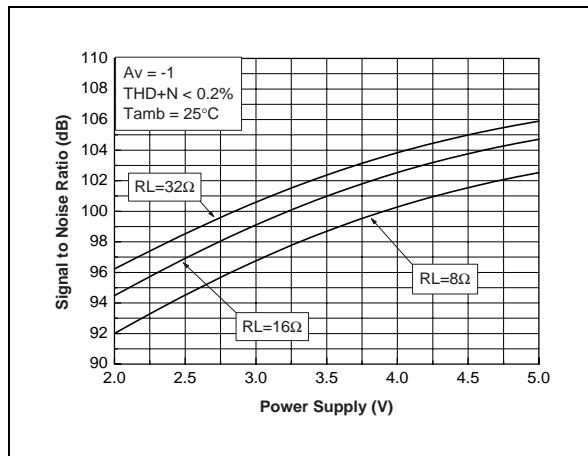


Fig. 56 : Signal to Noise Ratio vs Power Supply Voltage with Unweighted Filter (20Hz to 20kHz)

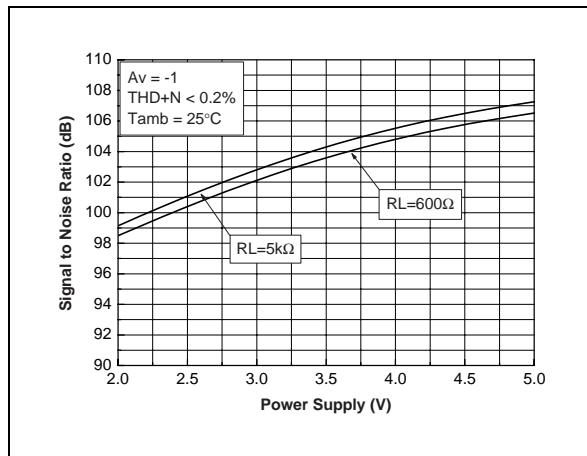


Fig. 57 : Signal to Noise Ratio vs Power Supply Voltage with Weighted Filter Type A

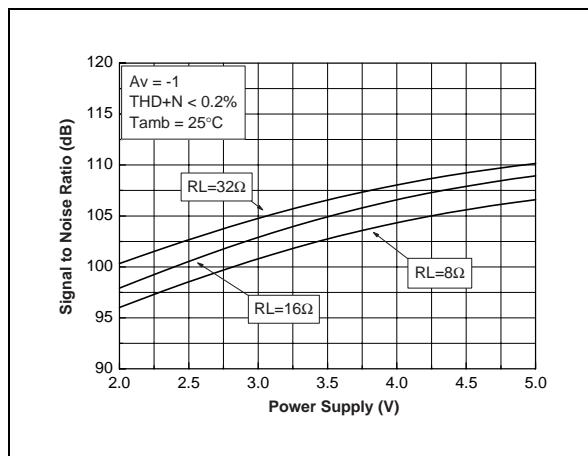


Fig. 58 : Signal to Noise Ratio vs Power Supply Voltage with Weighted Filter Type A

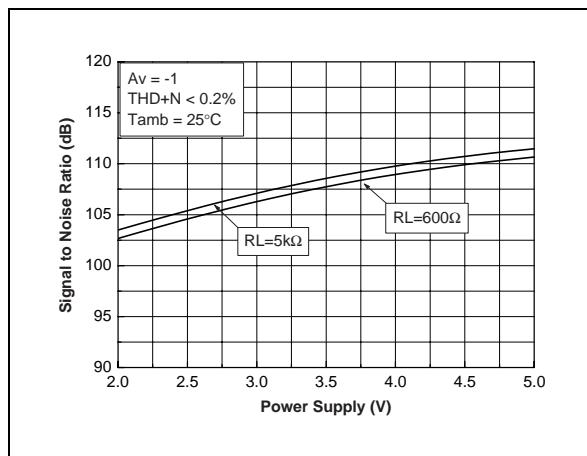


Fig. 59 : Equivalent Input Noise Voltage vs Frequency

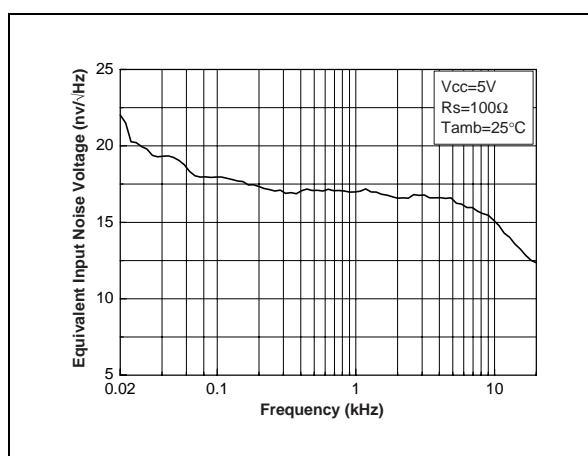
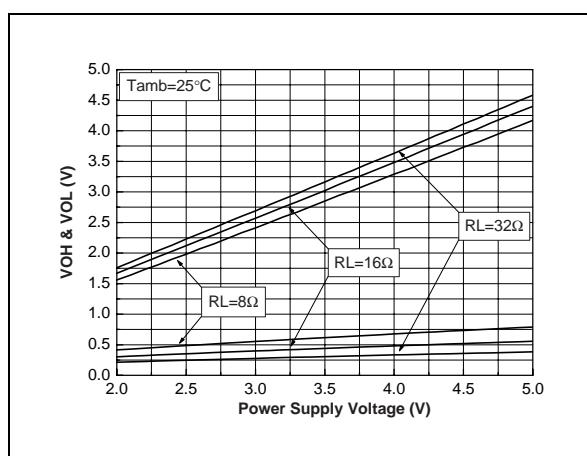


Fig. 60 : Output Voltage Swing vs Power Supply Voltage



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Fig. 61 : Crosstalk vs Frequency

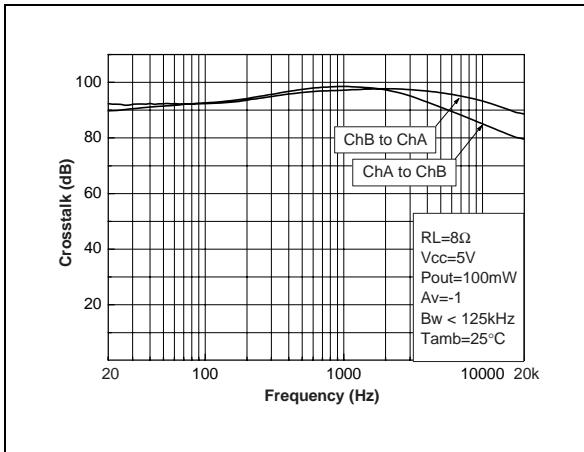


Fig. 62 : Crosstalk vs Frequency

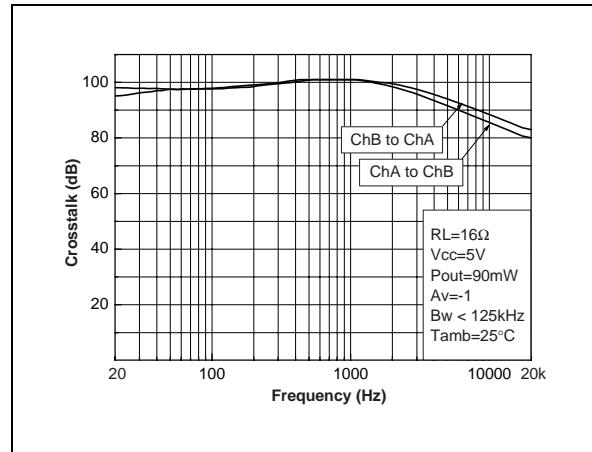


Fig. 63 : Crosstalk vs Frequency

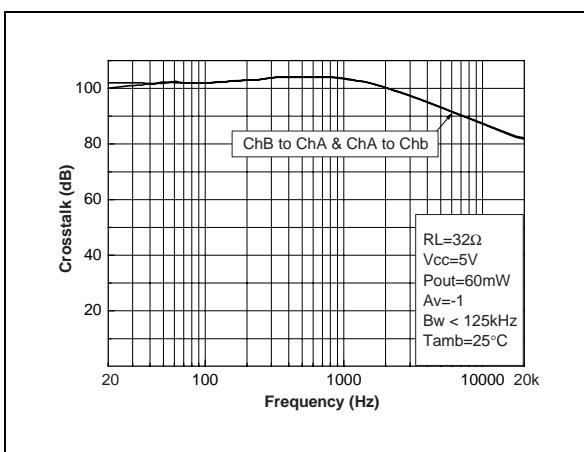


Fig. 64 : Crosstalk vs Frequency

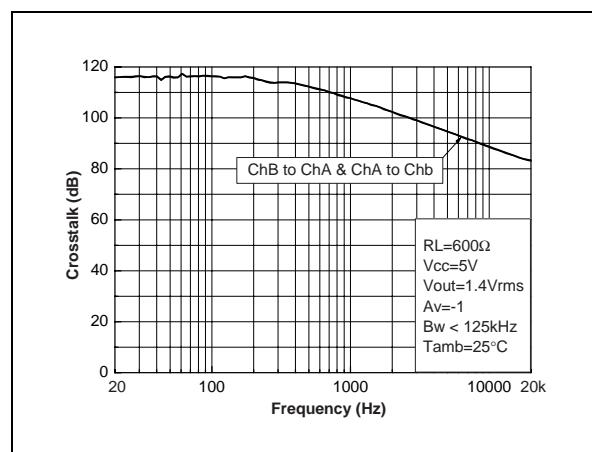


Fig. 65 : Crosstalk vs Frequency

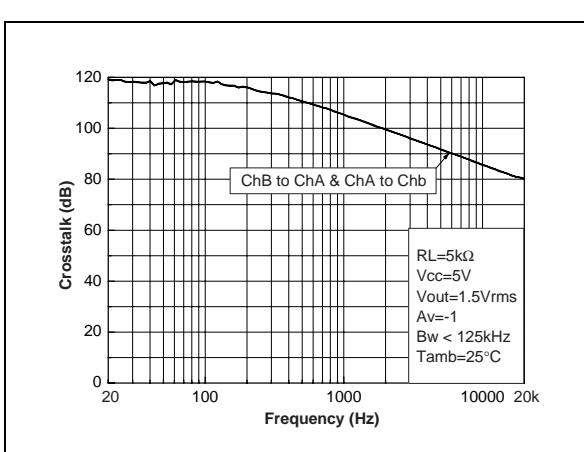


Fig. 66 : Lower Cut Off Frequency vs Output Capacitor

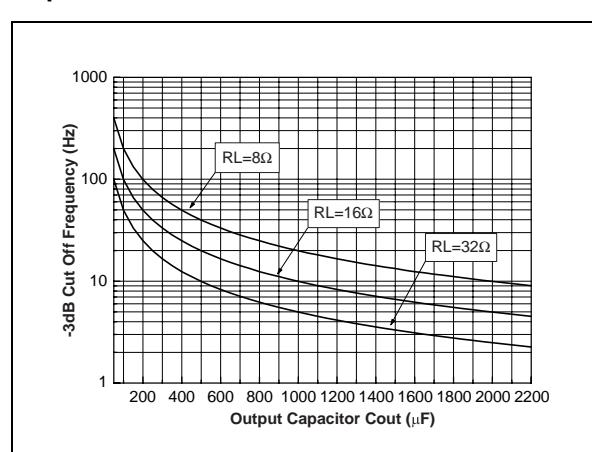


Fig. 67 : Lower Cut Off Frequency vs Input Capacitor

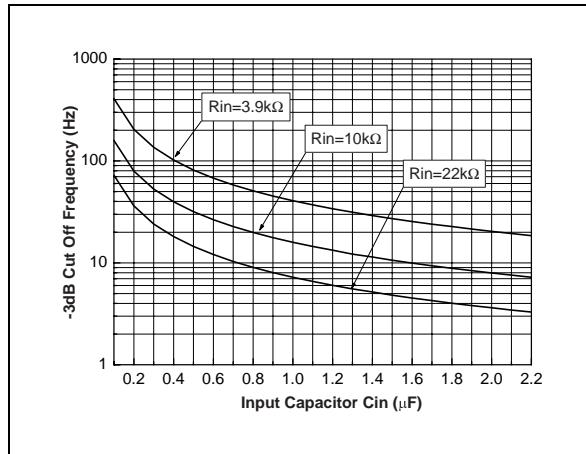


Fig. 68 : Typical Distribution of THD+N

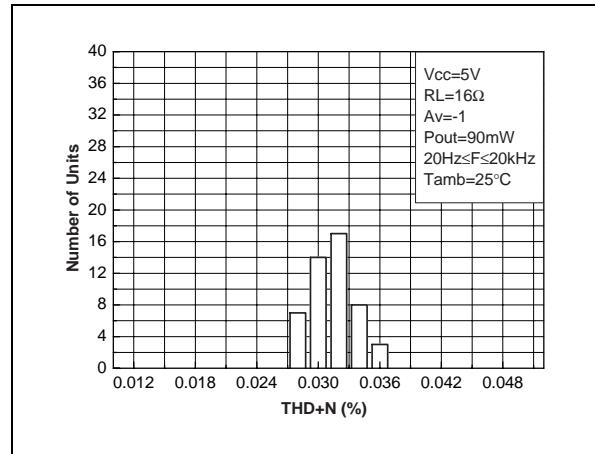


Fig. 69 : Best Case Distribution of THD+N

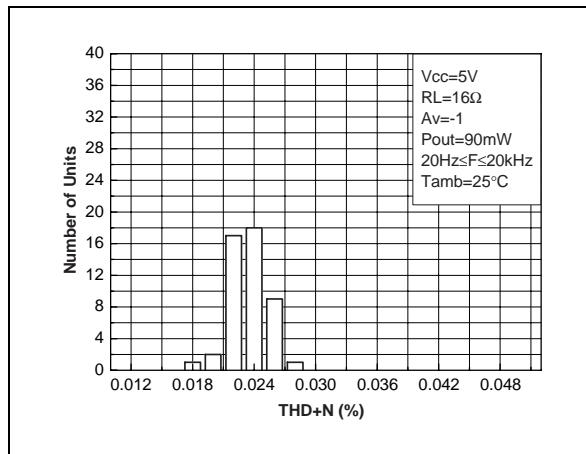


Fig. 70 : Worst Case Distribution of THD+N

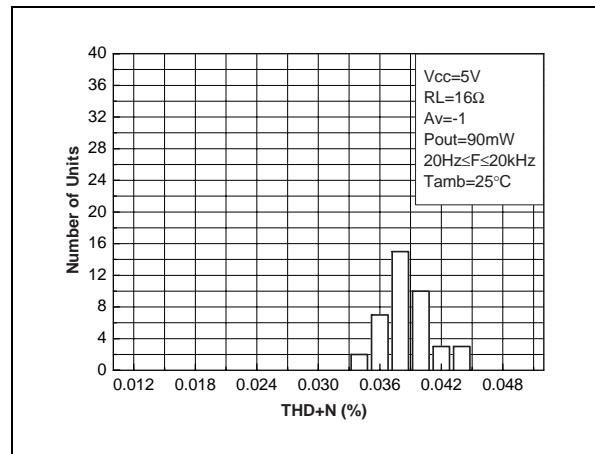


Fig. 71 : Typical Distribution of THD+N

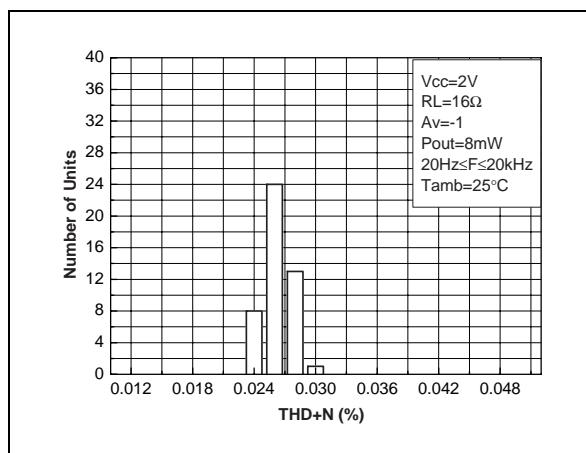


Fig. 72 : Best Case Distribution of THD+N

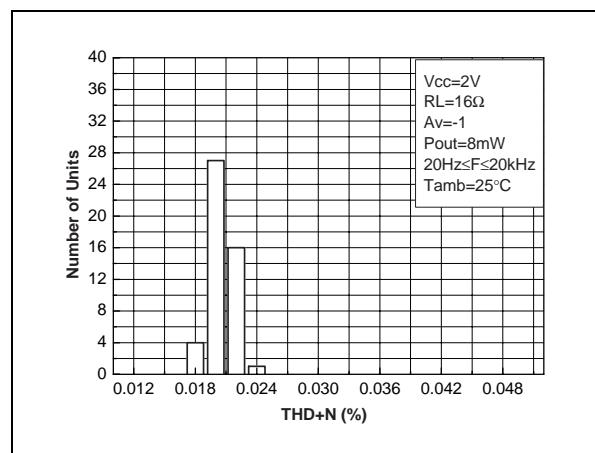


Fig. 73 : Worst Case Distribution of THD+N

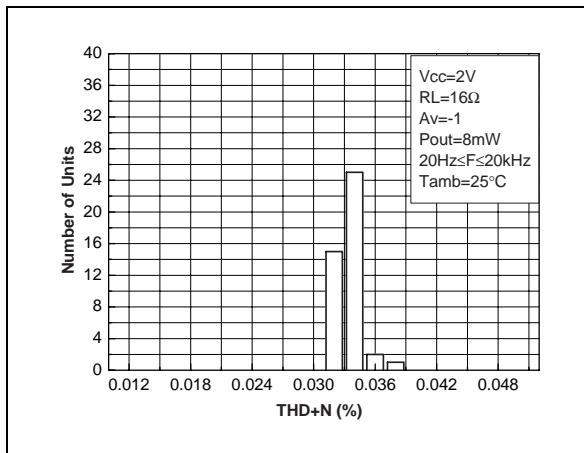


Fig. 74 : Typical Distribution of THD+N

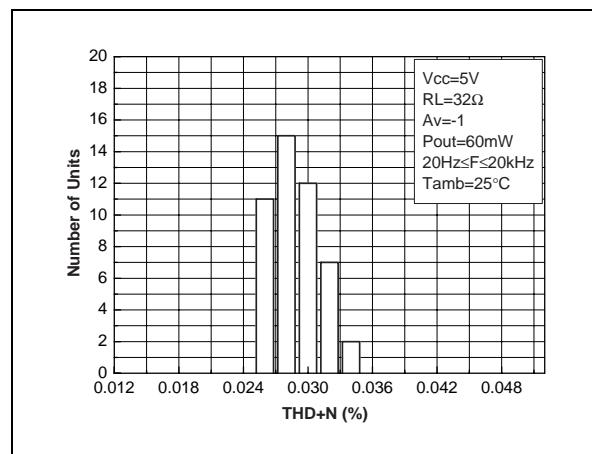


Fig. 75 : Best Case Distribution of THD+N

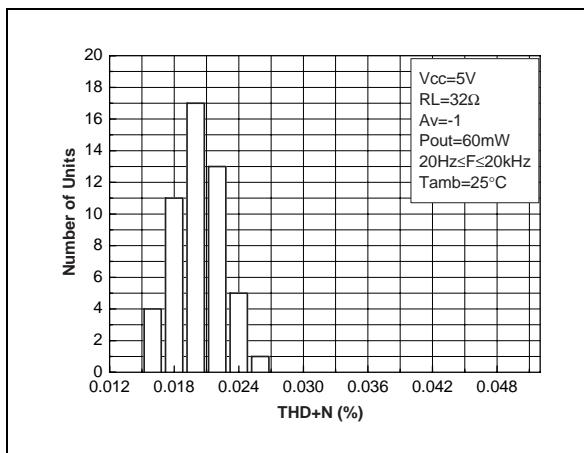


Fig. 76 : Worst Case Distribution of THD+N

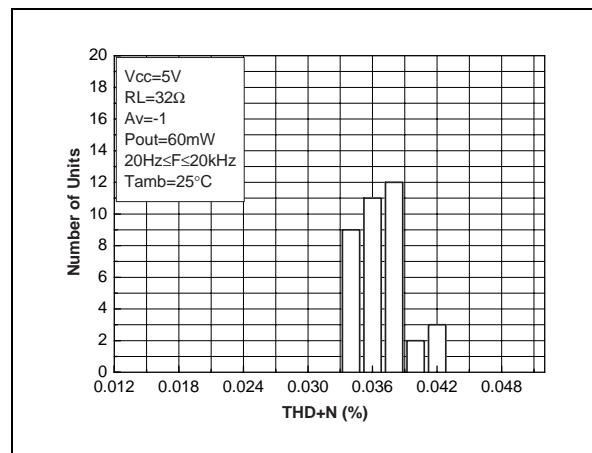


Fig. 77 : Typical Distribution of THD+N

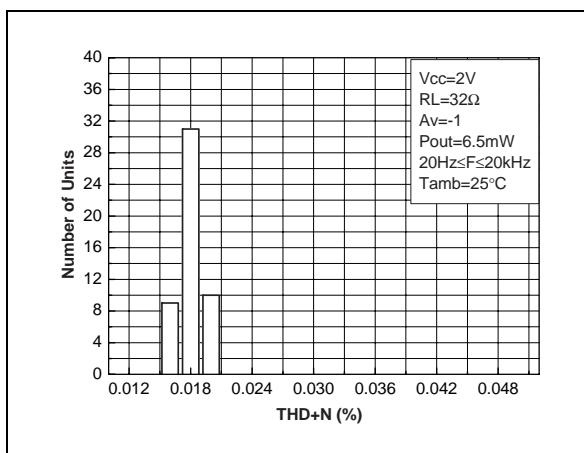


Fig. 78 : Best Case Distribution of THD+N

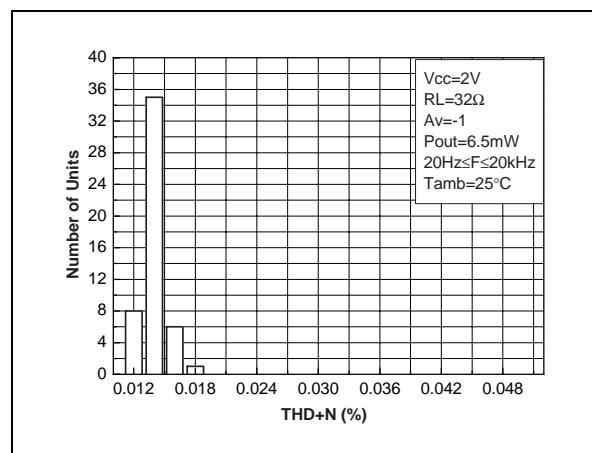
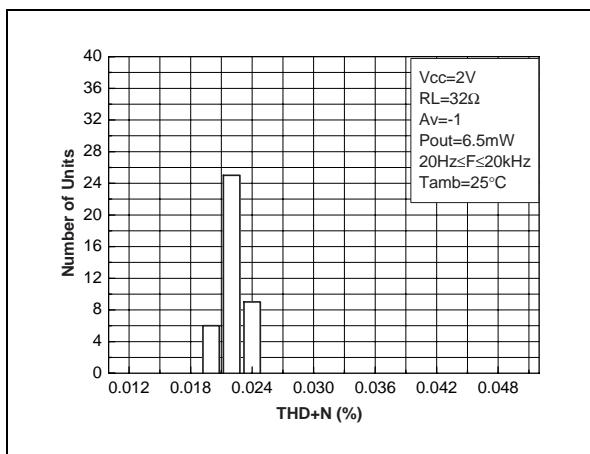
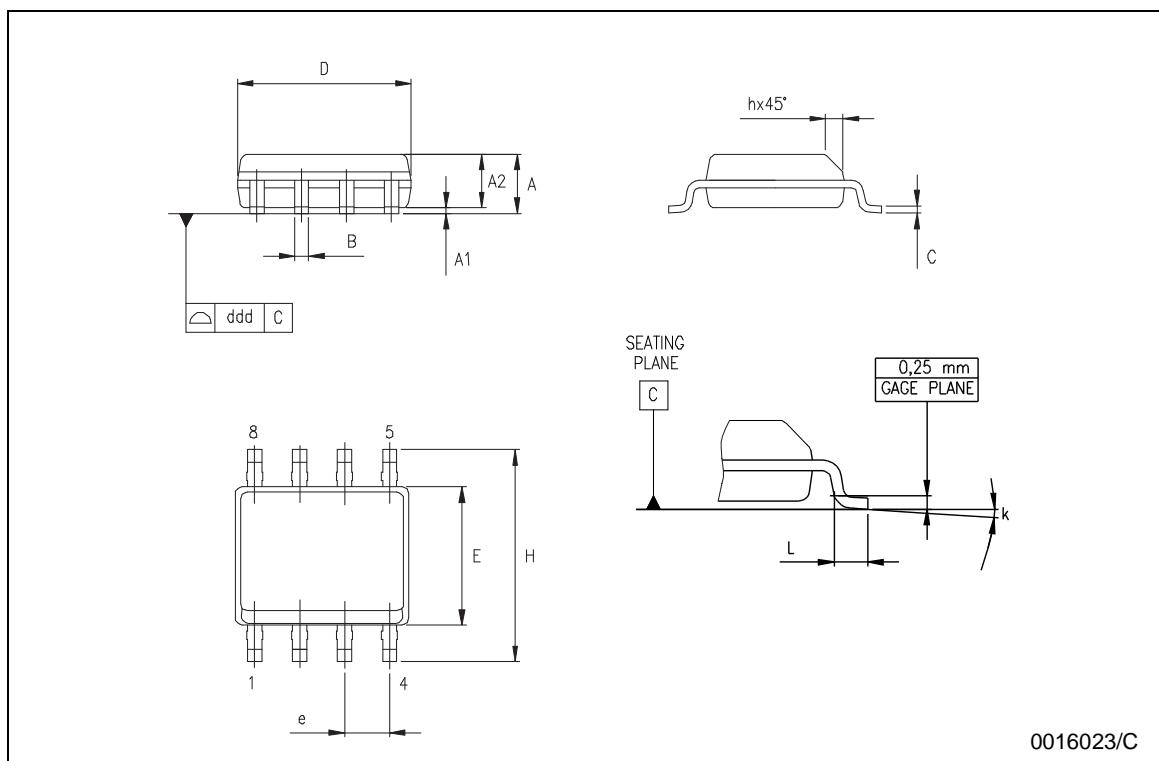


Fig. 79 : Worst Case Distribution of THD+N

PACKAGE MECHANICAL DATA

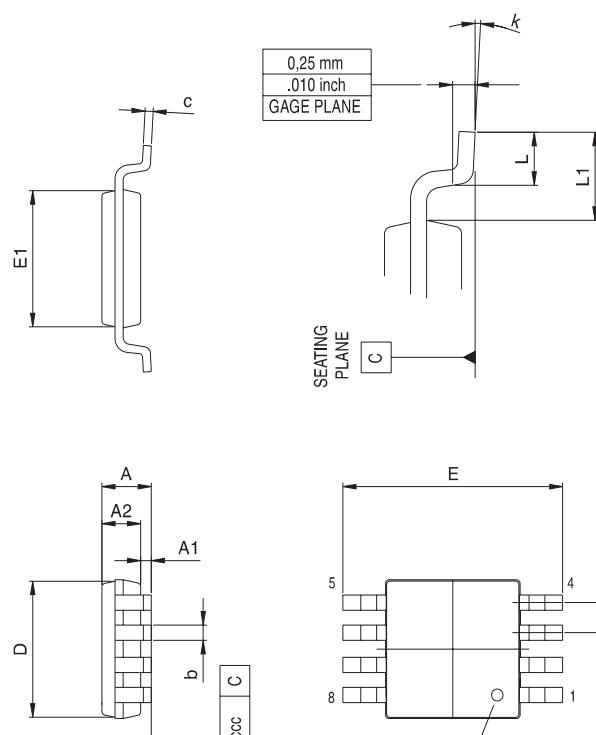
SO-8 MECHANICAL DATA

| DIM. | mm. | | | inch | | |
|------|-----------|------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 1.35 | | 1.75 | 0.053 | | 0.069 |
| A1 | 0.10 | | 0.25 | 0.04 | | 0.010 |
| A2 | 1.10 | | 1.65 | 0.043 | | 0.065 |
| B | 0.33 | | 0.51 | 0.013 | | 0.020 |
| C | 0.19 | | 0.25 | 0.007 | | 0.010 |
| D | 4.80 | | 5.00 | 0.189 | | 0.197 |
| E | 3.80 | | 4.00 | 0.150 | | 0.157 |
| e | | 1.27 | | | 0.050 | |
| H | 5.80 | | 6.20 | 0.228 | | 0.244 |
| h | 0.25 | | 0.50 | 0.010 | | 0.020 |
| L | 0.40 | | 1.27 | 0.016 | | 0.050 |
| k | 8° (max.) | | | | | |
| ddd | | | 0.1 | | | 0.04 |



PACKAGE MECHANICAL DATA

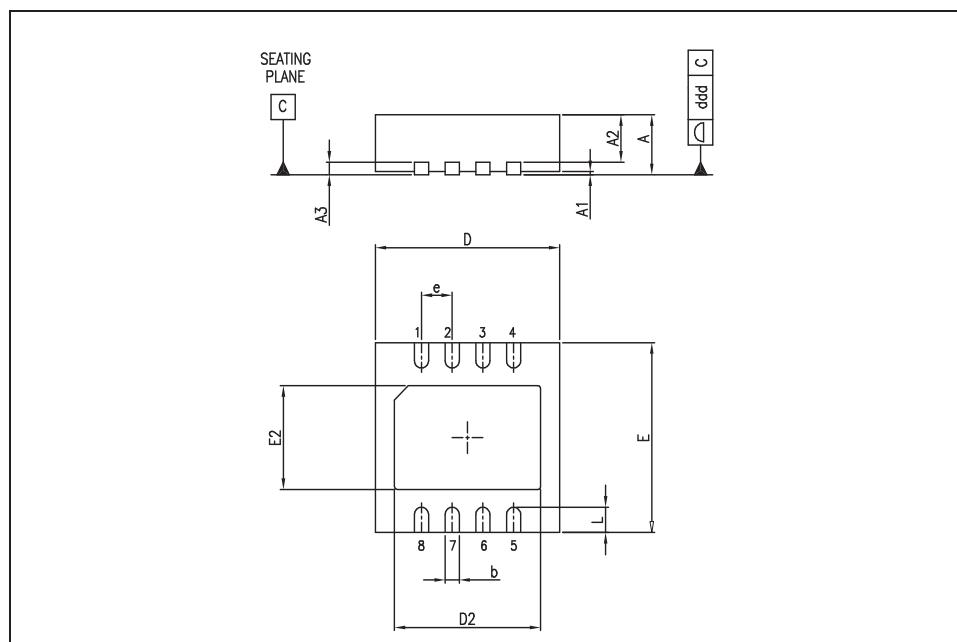
| DIM. | mm. | | | inch | | |
|------|------|------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 1.1 | | | 0.043 |
| A1 | 0.05 | 0.10 | 0.15 | 0.002 | 0.004 | 0.006 |
| A2 | 0.78 | 0.86 | 0.94 | 0.031 | 0.031 | 0.037 |
| b | 0.25 | 0.33 | 0.40 | 0.010 | 0.13 | 0.013 |
| c | 0.13 | 0.18 | 0.23 | 0.005 | 0.007 | 0.009 |
| D | 2.90 | 3.00 | 3.10 | 0.114 | 0.118 | 0.122 |
| E | 4.75 | 4.90 | 5.05 | 0.187 | 0.193 | 0.199 |
| E1 | 2.90 | 3.00 | 3.10 | .0114 | 0.118 | 0.122 |
| e | | 0.65 | | | 0.026 | |
| K | 0° | | 6° | 0° | | 6° |
| L | 0.40 | 0.55 | 0.70 | 0.016 | 0.022 | 0.028 |
| L1 | | | 0.10 | | | 0.004 |



PACKAGE MECHANICAL DATA

DFN8 (3x3) MECHANICAL DATA

| DIM. | mm. | | | inch | | |
|------|------|------|------|------|-------|------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 0.80 | 0.90 | 1.00 | 31.5 | 35.4 | 39.4 |
| A1 | | 0.02 | 0.05 | | 0.8 | 2.0 |
| A2 | | 0.70 | | | 27.6 | |
| A3 | | 0.20 | | | 7.9 | |
| b | 0.18 | 0.23 | 0.30 | 7.1 | 9.1 | 11.8 |
| D | | 3.00 | | | 118.1 | |
| D2 | 2.23 | 2.38 | 2.48 | 87.8 | 93.7 | 97.7 |
| E | | 3.00 | | | 118.1 | |
| E2 | 1.49 | 1.64 | 1.74 | 58.7 | 64.6 | 68.5 |
| e | | 0.50 | | | 19.7 | |
| L | 0.30 | 0.40 | 0.50 | 11.8 | 15.7 | 19.7 |



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